## **Dual High-Speed 1.5A MOSFET Drivers**

#### **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage VDD to GND	+20V
Time V <sub>IL</sub> < V <sub>IN</sub> < V <sub>I</sub> H	50ns
Input Voltage	V <sub>DD</sub> + 0.3V to GND - 0.3V
Continuous Power Dissipation (TA	$x = +70^{\circ}C$
Plastic DIP (derate 9.09mW/°C	above +70°C)727mW
SO (derate 5.88mW/°C above +	-70°C)471mW
CERDIP (derate 8.00mW/°C abo	ove +70°C)640mW

Operating Temperature Ranges:	
MAX442_C	0°C to +70°C
MAX442_E	40°C to +85°C
MAX442_MJA	550°C to +125°C
Storage Temperature Range	55°C to +160°C
Maximum Chip Temperature	+150°C
Lead Temperature (soldering, 10 sec)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS**

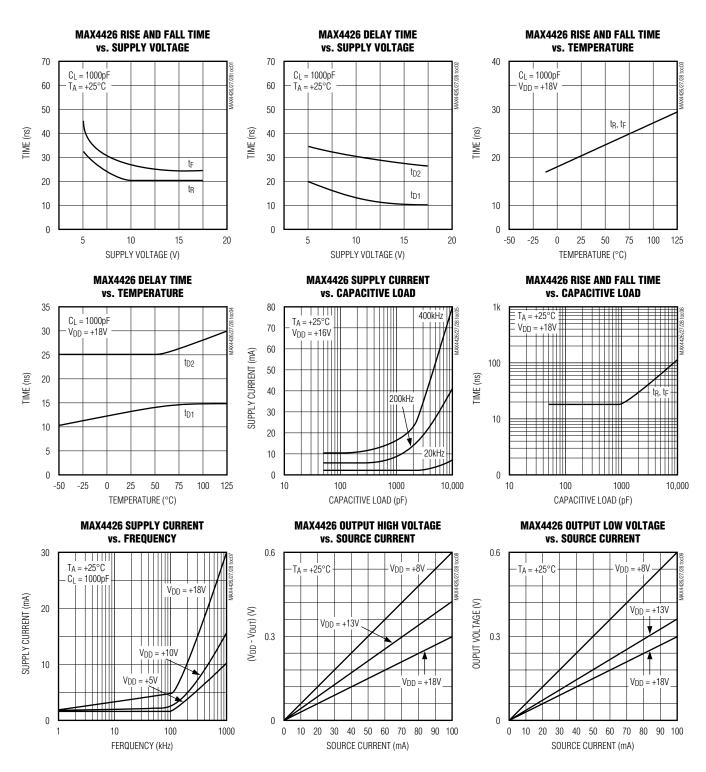
 $(V_{DD} = +4.5V \text{ to } +18V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified.})$ 

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS		
Logic 1 Input Voltage	VIH					2.4			V
Logic 0 Input Voltage	VIL							0.8	V
Input Current	liN	VIN = 0V to	VIN = 0V  to  18V		-1		1	μΑ	
Output High Voltage	Voн	No load		V <sub>DD</sub> - 25			mV		
Output Low Voltage	Vol	No load						25	mV
		V <sub>IN</sub> = 0.8V for inverting stages, V <sub>IN</sub> = 2.4V for noninverting stages  V <sub>DD</sub> = 18V, I <sub>LOAD</sub> =	inverting stage		T <sub>A</sub> = +25°C		4	10	
Output Resistance	Rout		TA = TMIN to TMAX		5	12	12 Ω		
Output Hosistanoo	10mA V <sub>IN</sub> = 2. inverting V <sub>IN</sub> = 0.	V <sub>IN</sub> = 2.4'	stages,	T <sub>A</sub> = +25°C		4	10	22	
			noninverting T <sub>A</sub> = T <sub>MI</sub>	T <sub>A</sub> = T <sub>MIN</sub> to		5	12		
Peak Output Current	Ipk	V <sub>DD</sub> = 18V	V <sub>DD</sub> = 18V			1.5		А	
		VIN = +3V fo	$V_{IN} = +3V$ for both $T_A =$		25°C		1.8	4.5	
Power Supply Current	loupp	inputs		TA = T	TA = TMIN  to  TMAX		2.5	8.0	mA
Power-Supply Current ISUPP VIN = 0	VIN = 0V for	$IN = OV \text{ for both}$ $T_A = +25^{\circ}C$			0.2	0.4			
		inputs	inputs $T_A = T_{MIN}$ to $T_{MAX}$			0.3	0.6		
Rise Time (Note 1)	t <sub>R</sub>	TA = +25°C TA = TMIN to TMAX			20	30	ns		
Thise time (Note 1)	'n				25	40	113		
   Fall Time (Note 1)	1) $t_F = \frac{T_A = +25^{\circ}C}{T_A = +25^{\circ}C}$	$T_A = +25^{\circ}C$ $T_A = T_{MIN}$ to $T_{MAX}$			20	30	ns		
Tall Timo (Note 1)	ч					25	40	1.0	
	t <sub>D1</sub>	TA = +25°C TA = TMIN to TMAX			10	30	ns		
Delay Time (Note 1)	101				15	40			
20.0, 11110 (11010 1)	t <sub>D2</sub>	$T_A = +25^{\circ}C$			25	50	ns		
		$T_A = T_{MIN}$ to $T_{MAX}$			30	60 '	110		

Note 1: Switching times guaranteed by design, not tested. See Figure 1 for timing measurement circuit.

# MAX4426/MAX4427/MAX4428 Dual High-Speed 1.5A MOSFET Drivers

#### **Typical Operating Characteristics**



## **Dual High-Speed 1.5A MOSFET Drivers**

#### **Applications Information**

The MAX4426/MAX4427/MAX4428 have easy-to-drive inputs. However, these inputs must never be allowed to stay between VIH and VIL for more than 50ns. Unused inputs should always be connected to ground to minimize supply current. Drivers can be paralleled on the MAX4426 or MAX4427 by tying both Inputs together and both outputs together.

Supply bypassing and grounding are extremely important with the MAX4426/MAX4427/MAX4428, as the peak supply current can be as high as 3A, which is twice the peak output current. Ground drops are a form of negative feedback with inverters, and hence will degrade the delay and transition time of the MAX4426/MAX4428.

Suggested bypass capacitors are a 4.7µF (low ESR) capacitor in parallel with a 0.1µF ceramic capacitor, mounted as close as possible to the MAX4426/ MAX4427/MAX4428. Use a ground plane if possible or separate ground returns for inputs and outputs. Output voltage ringing can be minimized with a  $5\Omega$  to  $20\Omega$  resistor in series with the output, but this will degrade output transition time. Ringing may be undesirable due to the large current that flows through capacitive loads when the voltage across these loads transitions quickly.

Operation at the upper end of the supply voltage range (> 15V) requires that a capacitance of at least 50pF be present at the outputs. This prevents the supply voltage provided to the die (which can be different from that seen at the supply pin) from exceeding the 20V absolute maximum rating, due to overshoot. Since at least 50pF of gate capacitance is present in all higher power FETs, this requirement is easily met.

#### **Power Dissipation**

The MAX4426/MAX4427/MAX4428 power dissipation consists of input inverter losses, crowbar current through the output devices, and output current (either capacitive or resistive). The sum of these must be kept below the maximum power dissipation limit.

The DC input inverter supply current is 0.2mA when both inputs are low and 2mA when both inputs are high. The crowbar current through an output device making a transition is approximately 100mA for a few nanoseconds. This is a small portion of the total supply current, except for high switching frequencies or a small load capacitance (100pF).

The MAX4426/MAX4427/MAX4428 power dissipation when driving a ground-referenced resistive load is:

$$P = (D) (ron(MAX)) (ILOAD^2)$$

where D is the percentage of time the MAX4426/MAX4427/MAX4428 output pulls high, ron(MAX) is the MAX4426/MAX4427/MAX4428 maximum on resistance, and ILOAD is the MAX4426/MAX4427/MAX4428 load current.

For capacitive loads, the power dissipation is:

$$P = (CLOAD) (VDD^2) (FREQ)$$

where  $C_{LOAD}$  is the capacitive load.  $V_{DD}$  is the MAX4426/ MAX4427/MAX4428 supply voltage, and FREQ is the toggle frequency.

# **Dual High-Speed 1.5A MOSFET Drivers**

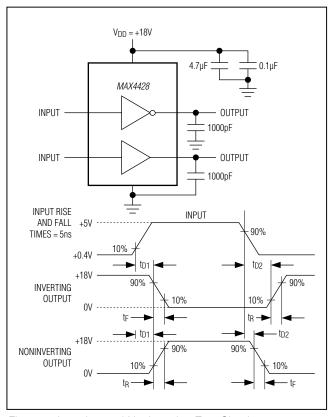


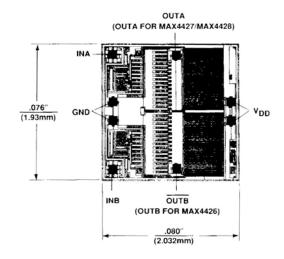
Figure 1. Inverting and Noninverting Test Circuit

### \_Ordering Information (continued)

PART	TEMP RANGE	PIN-PACKAGE
MAX4427CPA	0°C to +70°C	8 Plastic DIP
MAX4427CSA	0°C to +70°C	8 SO
MAX4427C/D	0°C to +70°C	Dice*
MAX4427EPA	-40°C to +85°C	8 Plastic DIP
MAX4427ESA	-40°C to +85°C	8 SO
MAX4427EJA	-40°C to +85°C	8 CERDIP
MAX4427MJA	-55°C to +125°C	8 CERDIP**
MAX4428CPA	0°C to +70°C	8 Plastic DIP
MAX4428CSA	0°C to +70°C	8 SO
MAX4428C/D	0°C to +70°C	Dice*
MAX4428EPA	-40°C to +85°C	8 Plastic DIP
MAX4428ESA	-40°C to +85°C	8 SO
MAX4428EJA	-40°C to +85°C	8 CERDIP
MAX4428MJA	-55°C to +125°C	8 CERDIP**

<sup>\*</sup>Dice are tested at  $T_A = +25$ °C.

#### Chip Topography



SUBSTRATE CONNECTED TO V<sub>DD</sub>; TRANSISTOR COUNT: 26.

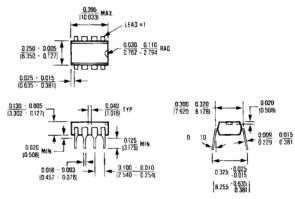
MAX4427/MAX4428

<sup>\*\*</sup>Contact factory for availability and processing to MIL-STD-883.

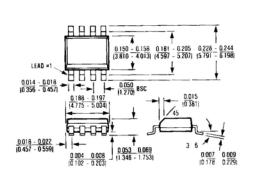
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#### Package Information

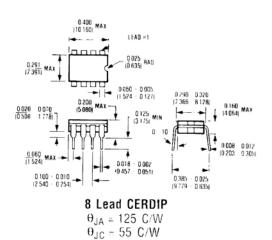
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <a href="https://www.maxim-ic.com/packages">www.maxim-ic.com/packages</a>.)



8 Lead Plastic DIP  $\theta_{JA} = 120^{\circ}\text{C/W}$   $\theta_{JC} = 70^{\circ}\text{C/W}$ 



8 Lead Small Outline  $\theta_{JA} = 170 \text{ C/W}$   $\theta_{JC} = 80 \text{ C/W}$ 



# MAX4426/MAX4427/MAX4428 Dual High-Speed 1.5A MOSFET Drivers

#### **Revision History**

REVISION	REVISION	DESCRIPTION	PAGES
NUMBER	DATE		CHANGED
2	6/06	To clarify and illuminate an input logic level restriction	_



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time. The parametric values (min and max limits) shown in the Electrical Characteristics table are guaranteed. Other parametric values quoted in this data sheet are provided for guidance.

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